## SMS3.3 3.3 Volt TVS Array For ESD and Latch-Up Protection

### PROTECTION PRODUCTS

### Description

The SMS series of TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD, lightning, and other voltage-induced transient events. Each device will protect up to four lines operating at **3.3 volts.** 

The SMS3.3 is a solid-state device designed specifically for transient suppression. It is constructed using Semtech's proprietary EPD process technology. The EPD process provides low standoff voltages with significant reductions in leakage currents and capacitance over traditional pn junction processes. They offer desirable characteristics for board level protection including fast response time, low clamping voltage and no device degradation.

The SMS3.3 may be used to meet the immunity requirements of IEC 61000-4-2, level 4 (±15kV air, ±8kV contact discharge). The low cost SOT23-6L package makes them ideal for use in portable electronics such as cell phones, PDA's, and notebook computers.

### **Features**

- Transient protection for data lines to
   IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
   IEC 61000-4-4 (EFT) 40A (5/50ns)
   IEC 61000-4-5 (Lightning) 12A (8/20μs)
- ◆ Protects four I/O lines
- Working voltage: 3.3V
- ◆ Low leakage current (<1µA)</p>
- Low clamping voltage
- ◆ Low capacitance (35pF typical)
- Solid-state EPD TVS technology

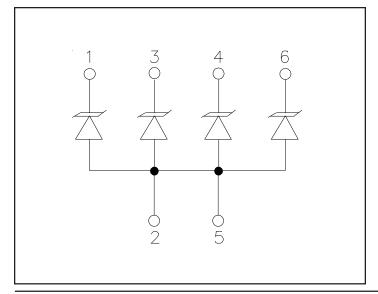
## Mechanical Characteristics

- ◆ EIAJ SOT23-6L package
- Molding compound flammability rating: UL 94V-0
- Marking : Marking Code
- Packaging : Tape and Reel per EIA 481

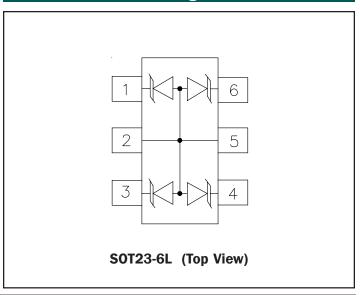
### **Applications**

- Cell phone Handsets and Accessories
- ◆ Microprocessor Based Equipment
- ◆ Personal Digital Assistants (PDA's) and Pagers
- Desktops PC and Servers
- Notebook, Laptop, and Palmtop Computers
- Portable Instrumentation
- Peripherals
- MP3 Players
- Cordless Phones

## **Equivalent Circuit Diagram**



## Schematic & PIN Configuration



рF

40

35



## PROTECTION PRODUCTS

## **Absolute Maximum Rating**

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20µs)	P <sub>pk</sub>	200	Watts
Peak Pulse Current (tp = 8/20µs)	I <sub>PP</sub>	12	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	>25 >15	kV
Soldering Temperature	T <sub>L</sub>	260 (10 seconds)	°C
Operating Temperature	T <sub>J</sub>	-55 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics**

Junction Capacitance

SMS3.3

#### **Symbol Conditions** Minimu-**Typical** Maximu-Unit-**Parameter** m m s Reverse Stand-Off Voltage $\mathbf{V}_{\mathsf{RWM}}$ 3.3 V Punch-Through Voltage $V_{\text{PT}}$ $I_{PT} = 2\mu A$ 3.5 V $I_{SB} = 50mA$ Snap-Back Voltage 2.8 V $V_{SB}$ $V_{RWM} = 3.3V, T=25$ °C Reverse Leakage Current 0.05 0.5 μΑ $I_R$ $I_{pp} = 1A$ , tp = 8/20 $\mu$ s Clamping Voltage 4.5 V $V_{c}$ Any I/O to Ground $I_{pp} = 5A$ , tp = 8/20 $\mu$ s Clamping Voltage V $V_c$ 6.8 Any I/O to Ground $I_{pp} = 12A$ , tp = 8/20 $\mu$ s Clamping Voltage $V_{c}$ 8.7 V Any I/O to Ground Steering Diode Forward Voltage $V_{\mathsf{F}}$ $I_{pp} = 1A$ , tp = 8/20 $\mu$ s 1.7 V (Reverse Clamping Voltage) Any I/O to Ground

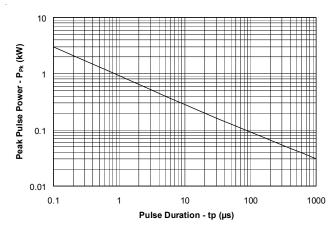
Each I/O pin and

Ground  $V_R = OV, f = 1MHz$ 

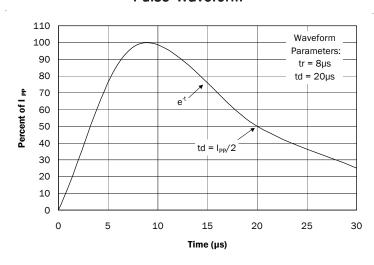
 $C_{i}$ 



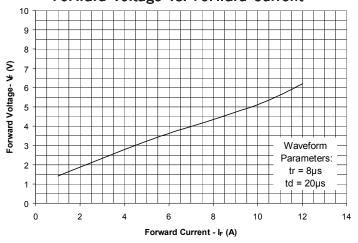
### Non-Repetitive Peak Pulse Power vs. Pulse Time



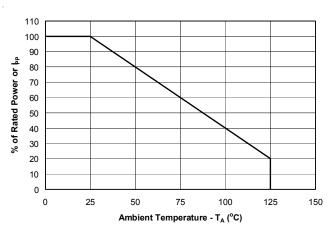
### **Pulse Waveform**



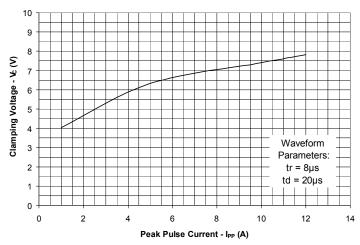
### Forward Voltage vs. Forward Current



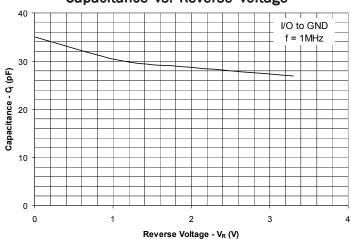
### **Power Derating**



### Clamping Voltage vs. Peak Pulse Current



### Capacitance vs. Reverse Voltage





## **Applications Information**

### **Device Connection for Protection of Four Data Lines**

The SMS3.3 is designed to protect up to four unidirectional data lines. The device is connected as follows:

 Unidirectional protection of four I/O lines is achieved by connecting pins 1, 3, 4 and 6 to the data lines. Pin 2 and 5 are connected to ground. The ground connections should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.

# Circuit Board Layout Recommendations for Suppression of ESD

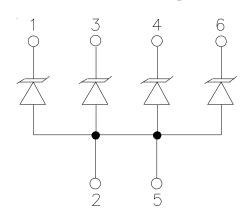
Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

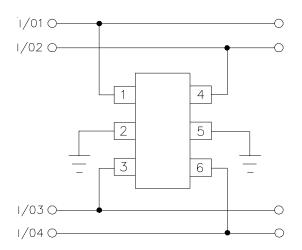
### **Matte Tin Lead Finish**

Matte tin has become the industry standard lead-free replacement for SnPb lead finishes. A matte tin finish is composed of 100% tin solder with large grains. Since the solder volume on the leads is small compared to the solder paste volume that is placed on the land pattern of the PCB, the reflow profile will be determined by the requirements of the solder paste. Therefore, these devices are compatible with both lead-free and SnPb assembly techniques. In addition, unlike other lead-free compositions, matte tin does not have any added alloys that can cause degradation of the solder joint.

### **SMS3.3 Circuit Diagram**

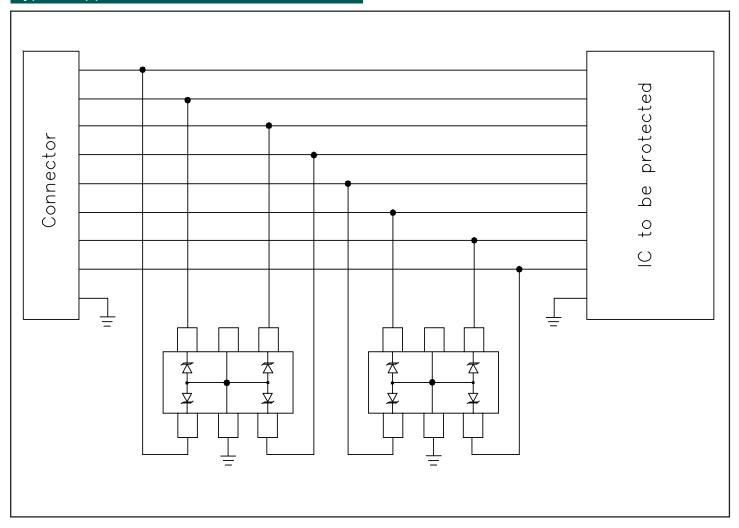


### **Protection of Four Unidirectional Lines**



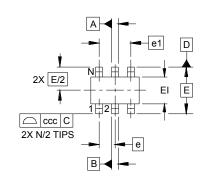


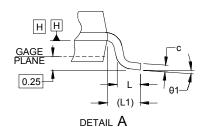
## Typical Applications

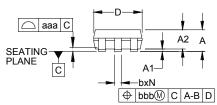


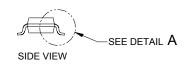


## Outline Drawing -SOT23 6L







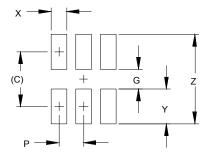


DIMENSIONS						
DIM	INCHES		MILLIMETERS			
וואווטן	MIN	NOM	MAX	MIN	NOM	MAX
Α	.035	-	.057	0.90	-	1.45
A1	.000	-	.006	0.00	-	0.15
A2	.035	.045	.051	.90	1.15	1.30
b	.010	-	.020	0.25	-	0.50
С	.003	-	.009	0.08	-	0.22
D	.110	.114	.118	2.80	2.90	3.00
E1	.060	.063	.069	1.50	1.60	1.75
E	.110 BSC		2.80 BSC			
е	.037 BSC		0.95 BSC			
e1	.075 BSC		1.90 BSC			
L	.012	.018	.024	0.30	0.45	0.60
L1	(.024)		(0.60)			
N	6		6			
<del>0</del> 1	0°	-	10°	0°	-	10°
aaa	.004		0.10			
bbb	.008		0.20			
CCC	.008		0.20			

### NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE-H-
- DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

## Land Pattern -SOT23 6L



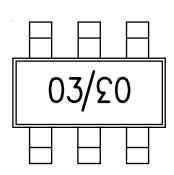
DIMENSIONS			
DIM	INCHES	MILLIMETERS	
С	(.098)	(2.50)	
G	.055	1.40	
Р	.037	0.95	
Х	.024	0.60	
Υ	.043	1.10	
Z	.141	3.60	

### NOTES:

THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
COMPANY'S MANUFACTURING GUIDELINES ARE MET.



## Marking



**Top Side Mark** 

## **Ordering Information**

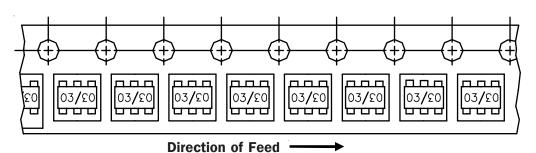
Part Number	Lead Finish	Qty per Reel	Reel Size
SMS3.3.TC	SnPb	3,000	7 Inch
SMS3.3.TCT	Pb free	3,000	7 Inch

### Note:

(1) No suffix indicates tube pack.

## Tape and Reel Specification

### **Device Orientation in Tape:**



### **Tape Specifications (per EIA 481)**

Reel Material: Static Dissipative
Tape Material: Static Dissipative
Tape Width: 8mm +/- 0.30mm
Component Pitch (max.): 4mm +/- 0.10mm

Component Cavity Play: 20°

## **Contact Information**

Semtech Corporation Protection Products Division 200 Flynn Rd., Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804